

## Features

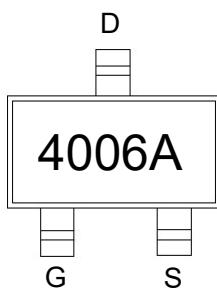
- Trench Power LV MOSFET technology
- High Density Cell Design for Low  $R_{DS(ON)}$
- High Speed switching

## Product Summary

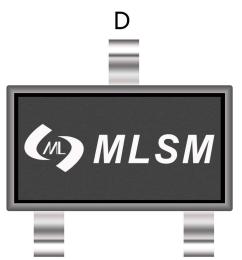
| $V_{DS}$ | $R_{DS(ON)} \text{ MAX}$ | $I_D \text{ MAX}$ |
|----------|--------------------------|-------------------|
| 40V      | 40mΩ@10V                 | 6A                |
|          | 50mΩ@4.5V                |                   |

## Application

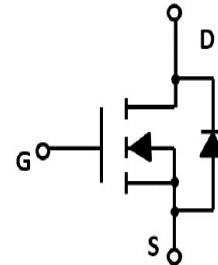
- CoBattery protection
- Load switch
- Power management



4006A: Device code



SOT-23-3L top view



Schematic diagram



Halogen-Free

Marking and pin assignment

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

## Common Ratings (TC=25°C Unless Otherwise Noted)

|           |                                  |            |    |
|-----------|----------------------------------|------------|----|
| $V_{DS}$  | Drain-Source Breakdown Voltage   | 40         | V  |
| $V_{GS}$  | Gate-Source Voltage              | ±20        | V  |
| $T_J$     | Maximum Junction Temperature     | 150        | °C |
| $T_{STG}$ | Storage Temperature Range        | -50 to 155 | °C |
| $I_S$     | Diode Continuous Forward Current | 6          | A  |

## Mounted on Large Heat Sink

|           |                                     |         |     |      |
|-----------|-------------------------------------|---------|-----|------|
| $I_{DM}$  | Pulse Drain Current Tested          | Tc=25°C | 26  | A    |
| $I_D$     | Continuous Drain Current            | Tc=25°C | 6   | A    |
| $P_D$     | Maximum Power Dissipation           | Tc=25°C | 1.2 | W    |
| $R_{θJA}$ | Thermal Resistance Junction-Ambient |         | 108 | °C/W |

## Ordering Information (Example)

| Type      | Package   | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|-----------|-----------|---------|----------------------|-------------------------|----------------------------|---------------|
| MLSK4006A | SOT-23-3L | 4006A   | 3,000                | 45,000                  | 180,000                    | 7" reel       |

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

| Symbol  | Parameter                        | Condition  | Min | Typ | Max  | Unit |
|---|----------------------------------|--|-----|-----|------|------|
| <b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b> |                                  |  |     |     |      |      |
| BV <sub>(BR)DSS</sub>   | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA               | 40  | --  | --   | V    |
| I <sub>DS</sub>   | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =40V, V <sub>GS</sub> =0V                | --  | --  | 1    | μA   |
| I <sub>GSS</sub>  | Gate-Body Leakage Current        | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V               | --  | --  | ±100 | nA   |
| V <sub>GS(th)</sub>   | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA | 1.0 | 1.5 | 2.5  | V    |
| R <sub>DS(on)</sub>   | Drain-Source On-State Resistance | V <sub>GS</sub> =10V, I <sub>D</sub> =5.6A               | --  | 30  | 40   | mΩ   |
|   |                                  | V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.5A              | --  | 38  | 50   | mΩ   |

**Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)**

|                  |                              |   |    |     |    |    |
|------------------|------------------------------|---|----|-----|----|----|
| C <sub>iss</sub> | Input Capacitance            | V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1MHz | -- | 490 | -- | pF |
| C <sub>oss</sub> | Output Capacitance           |   | -- | 42  | -- | pF |
| C <sub>RSS</sub> | Reverse Transfer Capacitance |   | -- | 33  | -- | pF |

**Switching Characteristics**

|                     |                     |   |    |      |    |    |
|---------------------|---------------------|---|----|------|----|----|
| Q <sub>g</sub>      | Total Gate Charge   | V <sub>DS</sub> =10V, I <sub>D</sub> =3A,<br>V <sub>GS</sub> =24V                     | -- | 10   | -- | nC |
| Q <sub>gs</sub>     | Gate Source Charge  |   | -- | 1.4  | -- | nC |
| Q <sub>gd</sub>     | Gate Drain Charge   |   | -- | 1.9  | -- | nC |
| t <sub>d(on)</sub>  | Turn-on Delay Time  |   | -- | 15   | -- | nS |
| t <sub>r</sub>      | Turn-on Rise Time   | V <sub>DS</sub> =24V, I <sub>D</sub> =2A,<br>V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω | -- | 49.5 | -- | nS |
| t <sub>d(off)</sub> | Turn-Off Delay Time |   | -- | 19.2 | -- | nS |
| t <sub>f</sub>      | Turn-Off Fall Time  |   | -- | 11   | -- | nS |

**Source- Drain Diode Characteristics**

|                 |                    |  |    |    |     |   |
|-----------------|--------------------|--|----|----|-----|---|
| V <sub>SD</sub> | Forward on voltage | T <sub>J</sub> =25°C, I <sub>S</sub> =6A | -- | -- | 1.2 | V |
|-----------------|--------------------|--|----|----|-----|---|

### Typical Operating Characteristics

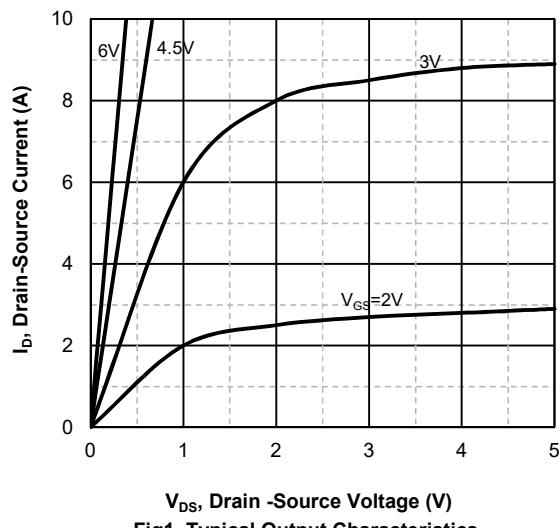


Fig1. Typical Output Characteristics

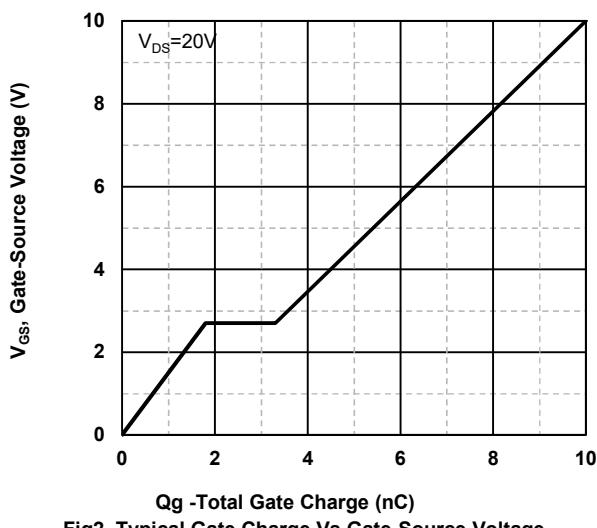


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

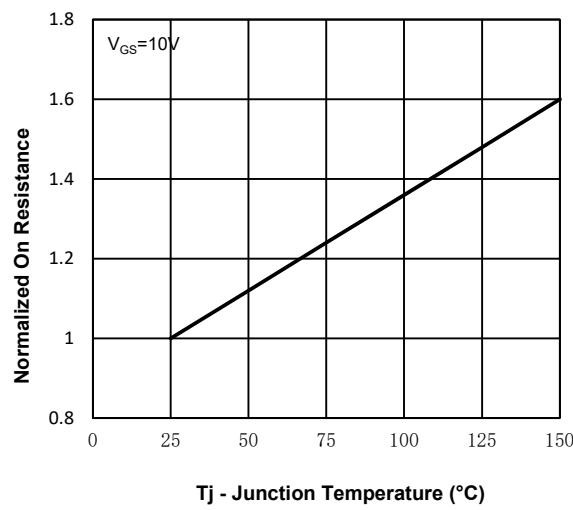


Fig3. Normalized On-Resistance Vs. Temperature

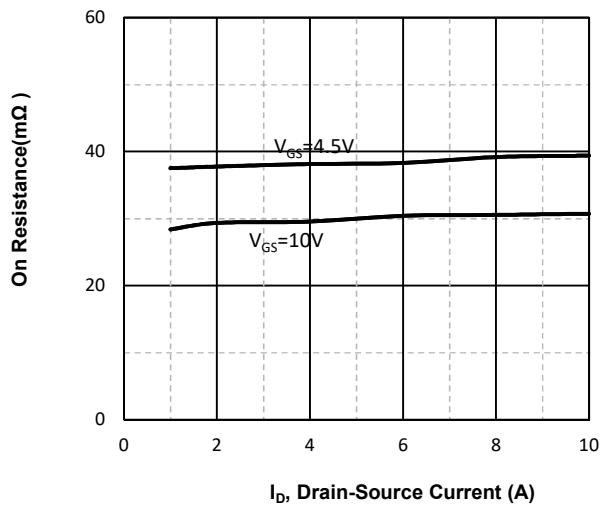


Fig4. On-Resistance Vs. Drain-Source Current

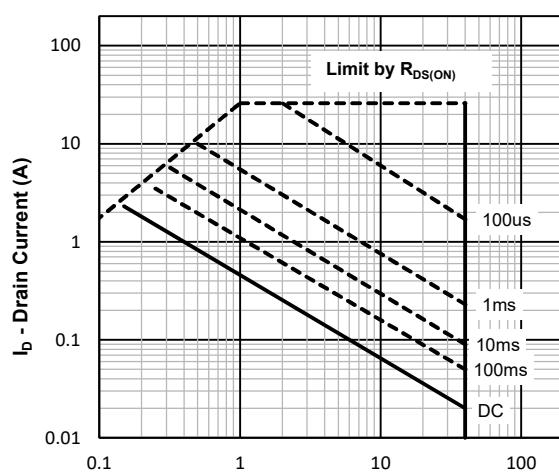


Fig5. Maximum Safe Operating Area

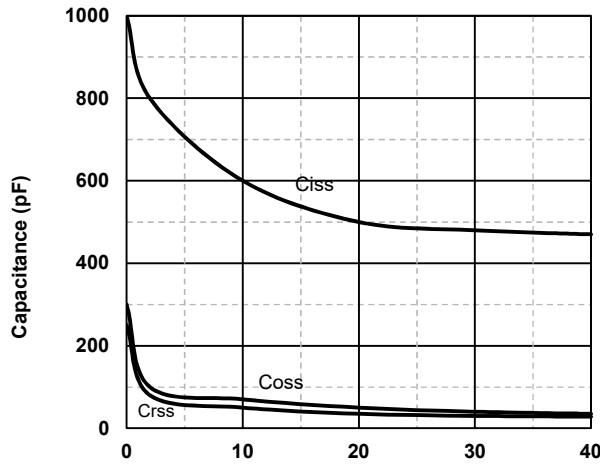
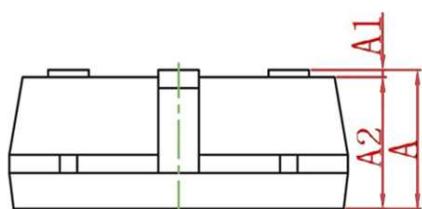
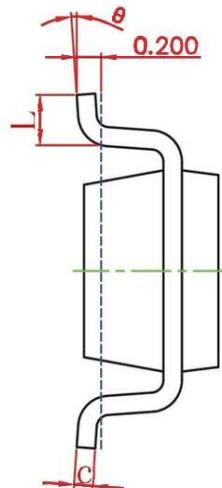
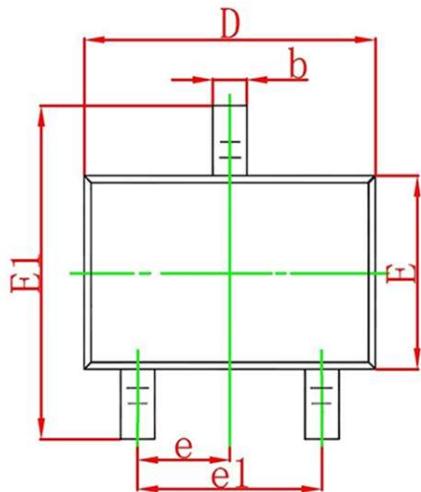


Fig6 Typical Capacitance Vs.Drain-Source Voltage

## SOT-23-3L Package information



| Symbol | Dimensions in Millimeters(mm) |       | Dimensions in Inches |       |
|--------|-------------------------------|-------|----------------------|-------|
|        | Min                           | Max   | Min                  | Max   |
| A      | 1.050                         | 1.250 | 0.042                | 0.050 |
| A1     | 0.000                         | 0.100 | 0.000                | 0.004 |
| A2     | 1.050                         | 1.150 | 0.042                | 0.046 |
| b      | 0.300                         | 0.500 | 0.012                | 0.020 |
| c      | 0.100                         | 0.200 | 0.004                | 0.008 |
| D      | 2.820                         | 3.020 | 0.112                | 0.120 |
| E      | 1.500                         | 1.700 | 0.060                | 0.068 |
| E1     | 2.650                         | 2.950 | 0.106                | 0.118 |
| e      | 0.950TYP                      |       | 0.037TYP             |       |
| e1     | 1.800                         | 2.000 | 0.071                | 0.079 |
| L      | 0.300                         | 0.600 | 0.012                | 0.024 |
| θ      | 0°                            | 8°    | 0°                   | 8°    |